



**CRYSTAL OSCILLATORS, CLASS 2, 4MHz TO 100MHz,  
AHCMOS COMPATIBLE OUTPUT, RAD-HARD**

**BASED ON TYPE RK135**

**ESCC Detail Specification No. 3503/001**

Issue 2	April 2020
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1254	Specification upissued to incorporate changes per DCR

**TABLE OF CONTENTS**

1	GENERAL	5
1.1	SCOPE	5
1.2	APPLICABLE DOCUMENTS	5
1.3	TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS	5
1.4	THE ESCC COMPONENT NUMBER AND COMPONENT TYPE VARIANTS	5
1.4.1	The ESCC Component Number	5
1.4.2	Characteristics Codes	5
1.4.3	Component Type Variants	6
1.5	MAXIMUM RATINGS	7
1.6	PHYSICAL DIMENSIONS AND TERMINAL IDENTIFICATION	8
1.6.1	Flat Package (FP1) – 14 leads	8
1.6.2	Flat Package (FP2) – 20 leads	9
1.6.3	Flat Package (FP3) – 12 leads	10
1.6.4	Flat Package (FP4) – 16 leads	11
1.6.5	Dual-in-Line Package (DIL1) – 14 leads	12
1.6.6	J-Lead Package (JL2) – 4 leads	13
1.7	FUNCTIONAL DIAGRAM	14
1.8	MATERIALS AND FINISHES	14
2	REQUIREMENTS	15
2.1	GENERAL	15
2.1.1	Oscillator Class	15
2.1.2	Deviations from the Generic Specification	15
2.2	MARKING	15
2.3	ELECTRICAL MEASUREMENTS AT ROOM, HIGH AND LOW TEMPERATURES	16
2.3.1	Room Temperature Electrical Measurements	16
2.3.2	High and Low Temperatures Electrical Measurements	17
2.3.3	Notes to Paras. 2.3.1 and 2.3.2 Room, High and Low Electrical Measurements	17
2.4	PARAMETER DRIFT VALUES	18
2.5	INTERMEDIATE AND END-POINT ELECTRICAL MEASUREMENTS	19
2.6	BURN-IN CONDITIONS	19
2.7	FREQUENCY AGEING CONDITIONS	20
2.8	OPERATING LIFE CONDITIONS	20
2.9	TOTAL DOSE RADIATION TESTING	20
2.9.1	Bias Conditions and Total Dose Level for Total Dose Radiation Testing	20
2.9.2	Electrical Measurements for Total Dose Radiation Testing	21

**1 GENERAL**

**1.1 SCOPE**

This specification details the ratings, physical and electrical characteristics and test and inspection data for the component type variants and/or the range of components specified below. It supplements the requirements of, and shall be read in conjunction with, the ESCC Generic Specification listed under Applicable Documents.

**1.2 APPLICABLE DOCUMENTS**

The following documents form part of this specification and shall be read in conjunction with it:

- (a) ESCC Generic Specification No. [3503](#).

**1.3 TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS**

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESCC Basic Specification No. [21300](#) shall apply.

**1.4 THE ESCC COMPONENT NUMBER AND COMPONENT TYPE VARIANTS**

**1.4.1 The ESCC Component Number**

The ESCC Component Number shall be constituted as follows:

Example: 350300101R100M000000

- Detail Specification Reference: 3503001
- Component Type Variant Number: 01 (as required)
- Total Dose Radiation Level Letter (100krad(Si)): R (as required)
- Characteristic code: Nominal Frequency (100MHz): 100M000000 (as required)

**1.4.2 Characteristics Codes**

Characteristics to be codified as part of the ESCC Component Number shall be as follows:

- (a) Nominal Frequency expressed by means of the following codes. The unit quantity shall be MHz:

Nominal Frequency $f_{Nom}$ (MHz)	Code
X.XXXXXX	XMXXXXXX
XX.XXXXXX	XXMXXXXXX
XXX.XXXXXX	XXXMXXXXXX

1.4.3 Component Type Variants

The component type variants applicable to this specification are as follows:

Variant Number	Nominal Output Frequency $f_{Nom}$ (MHz)	Case	Nominal Supply Voltage $V_{CCNom}$ (V)	Terminal Material and Finish	Weight max g	Total Dose Radiation Level Letter
01	4 to 100	FP1	3.3	D2	5	R [100krad(Si)]
02	4 to 100	FP2	3.3	D2	5	R [100krad(Si)]
03	4 to 100	FP3	3.3	D2	5	R [100krad(Si)]
04	4 to 100	FP4	3.3	D2	5	R [100krad(Si)]
05	4 to 100	DIL1	3.3	G2	5	R [100krad(Si)]
06	4 to 100	JL2	3.3	D2	2	R [100krad(Si)]
07	4 to 100	FP1	5	D2	5	R [100krad(Si)]
08	4 to 100	FP2	5	D2	5	R [100krad(Si)]
09	4 to 100	FP3	5	D2	5	R [100krad(Si)]
10	4 to 100	FP4	5	D2	5	R [100krad(Si)]
11	4 to 100	DIL1	5	G2	5	R [100krad(Si)]
12	4 to 100	JL2	5	D2	2	R [100krad(Si)]

The terminal material and finish shall be in accordance with the requirements of ESCC Basic Specification No. [23500](#).

Total dose radiation level letters are defined in ESCC Basic Specification No. [22900](#). If an alternative radiation test level is specified in the Purchase Order the letter shall be changed accordingly.

1.5 MAXIMUM RATINGS

The maximum ratings shall not be exceeded at any time during use or storage.

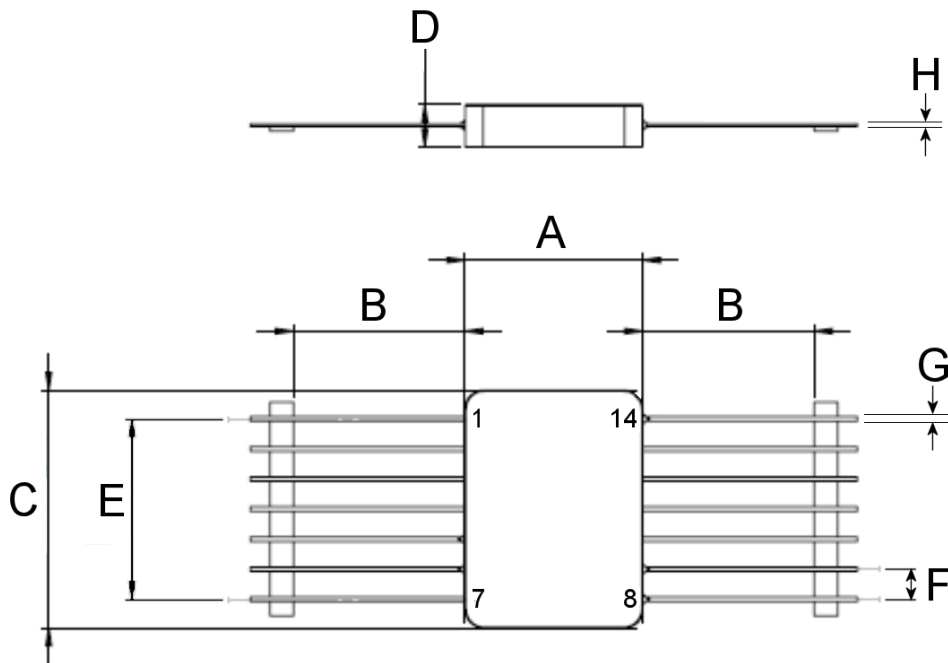
Maximum ratings shall only be exceeded during testing to the extent specified in this specification and when stipulated in Test Methods and Procedures of the ESCC Generic Specification.

Characteristics	Symbols	Maximum Ratings	Unit	Remarks
Supply Voltage	$V_{CC}$	-0.5 to +7	V	Note 1
Load Impedance	$C_L$	50	pF	Note 2
Operating Temperature Range	$T_{op}$	-55 to +110	°C	$T_{amb}$
Storage Temperature Range	$T_{stg}$	-55 to +110	°C	
Soldering Temperature	$T_{sol}$	+260	°C	Note 3

**NOTES:**

1. Device is functional as follows:
  - Variants 01 to 06:  $+2.97V \leq V_{CC} \leq +3.63V$  (where nominal  $V_{CC}$ ,  $V_{CCNom} = +3.3V$ )
  - Variants 07 to 12:  $+4.5V \leq V_{CC} \leq +5.5V$  (where nominal  $V_{CC}$ ,  $V_{CCNom} = +5V$ )
2. Device is functional as follows:
  - Variants 01 to 06:
    - For  $4MHz \leq f_{Nom} < 80MHz$ :  $C_{LMin} = 13pF \leq C_L \leq C_{LMax} = 18pF$  (load in parallel with  $R_L = 1k\Omega$ ) (where nominal  $C_L$ ,  $C_{LNom} = 15pF$ )
    - For  $80MHz \leq f_{Nom} \leq 100MHz$ :  $C_{LMin} = 8.2pF \leq C_L \leq C_{LMax} = 11pF$  (load in parallel with  $R_L = 1k\Omega$ ) (where nominal  $C_L$ ,  $C_{LNom} = 10pF$ )
  - Variants 07 to 12:  $C_{LMin} = 13pF \leq C_L \leq C_{LMax} = 18pF$  (load in parallel with  $R_L = 1k\Omega$ ) (where nominal  $C_L$ ,  $C_{LNom} = 15pF$ )
3. Hand soldering: duration 10 seconds maximum at a distance of not less than 1.5mm from the device body and the same lead shall not be resoldered until 3 minutes have elapsed.

1.6 PHYSICAL DIMENSIONS AND TERMINAL IDENTIFICATION

 1.6.1 Flat Package (FP1) – 14 leads


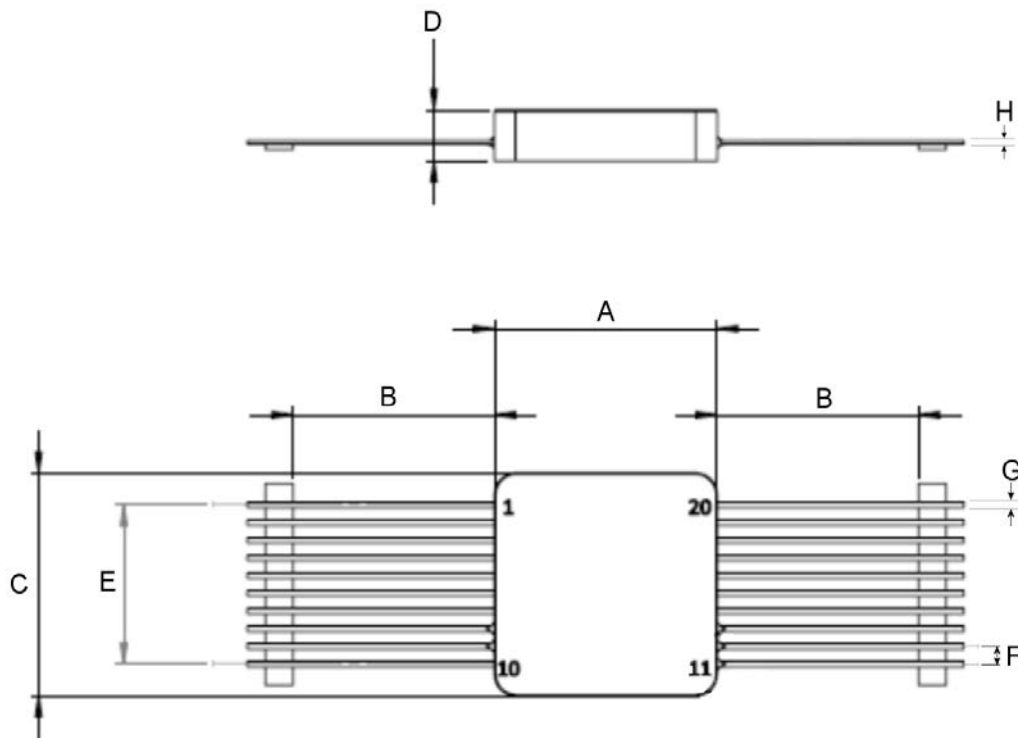
Symbols	Dimensions mm		Notes
	Min	Max	
A	14.86	15.12	
B	14	15	
C	19.94	20.2	
D	-	3.71	
E	15.24 BSC		2 places
F	2.54 BSC		All leads
G	0.28	0.48	All leads
H	0.15	0.35	All leads

**NOTES:**

- The terminal identification is specified by marking of the terminal number on the lid as shown. See Para. 1.7 for the terminal connections.



1.6.2 Flat Package (FP2) – 20 leads

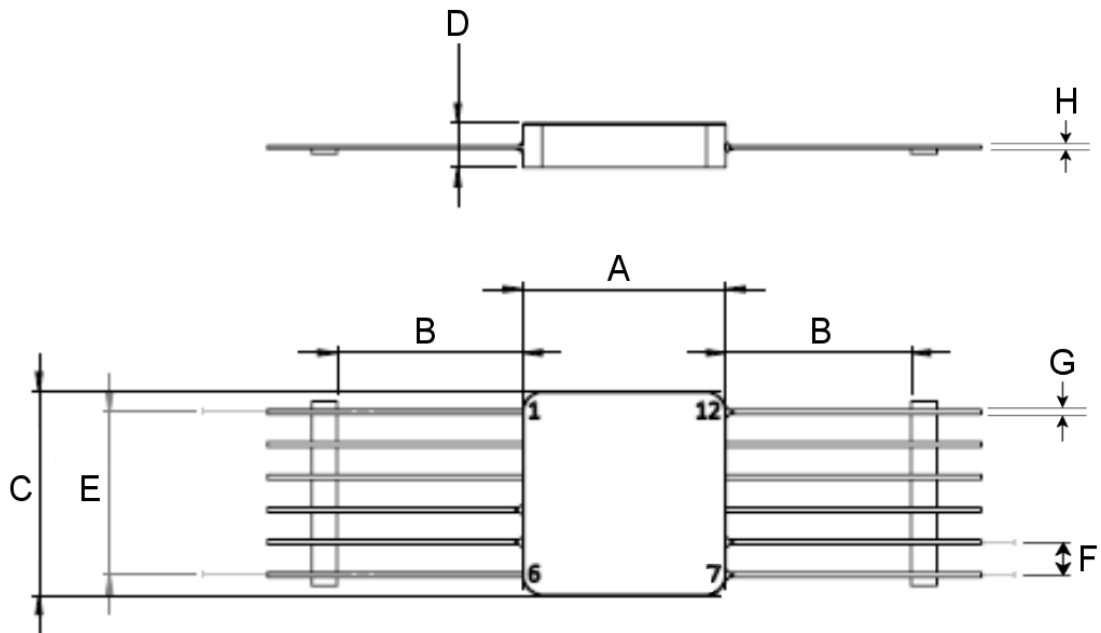


Symbols	Dimensions mm		Notes
	Min	Max	
A	15.75	16.01	
B	14	15	
C	15.75	16.01	
D	-	3.83	
E	11.43 BSC		2 places
F	1.27 BSC		All leads
G	0.28	0.48	All leads
H	0.15	0.35	All leads

**NOTES:**

1. The terminal identification is specified by marking of the terminal number on the lid as shown. See Para. 1.7 for the terminal connections.

1.6.3 Flat Package (FP3) – 12 leads

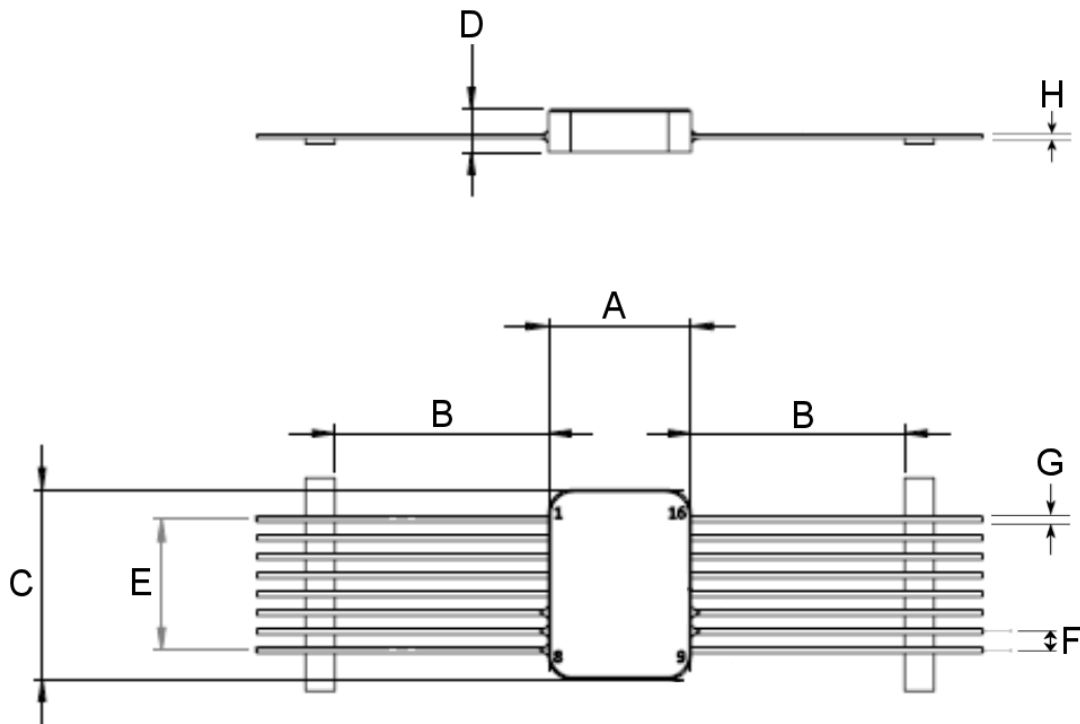


Symbols	Dimensions mm		Notes
	Min	Max	
A	15.75	16.01	
B	14	15	
C	15.75	16.01	
D	-	3.58	
E	12.7 BSC		2 places
F	2.54 BSC		All leads
G	0.28	0.48	All leads
H	0.15	0.35	All leads

**NOTES:**

- The terminal identification is specified by marking of the terminal number on the lid as shown. See Para. 1.7 for the terminal connections.

## 1.6.4 Flat Package (FP4) – 16 leads

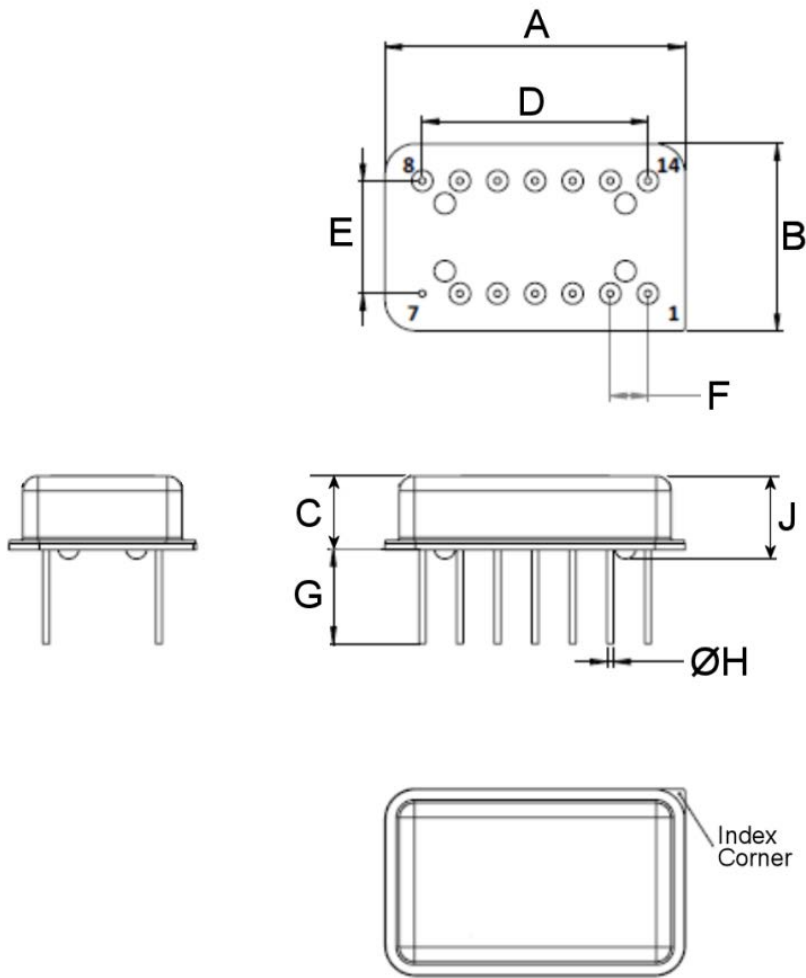


Symbols	Dimensions mm		Notes
	Min	Max	
A	-	9.66	
B	13.9	15.1	
C	-	12.83	
D	-	3.1	
E	8.89 BSC		2 places
F	1.27 BSC		All leads
G	0.28	0.48	All leads
H	0.15	0.35	All leads

**NOTES:**

- The terminal identification is specified by marking of the terminal number on the lid as shown. See Para. 1.7 for the terminal connections.

1.6.5 Dual-in-Line Package (DIL1) – 14 leads

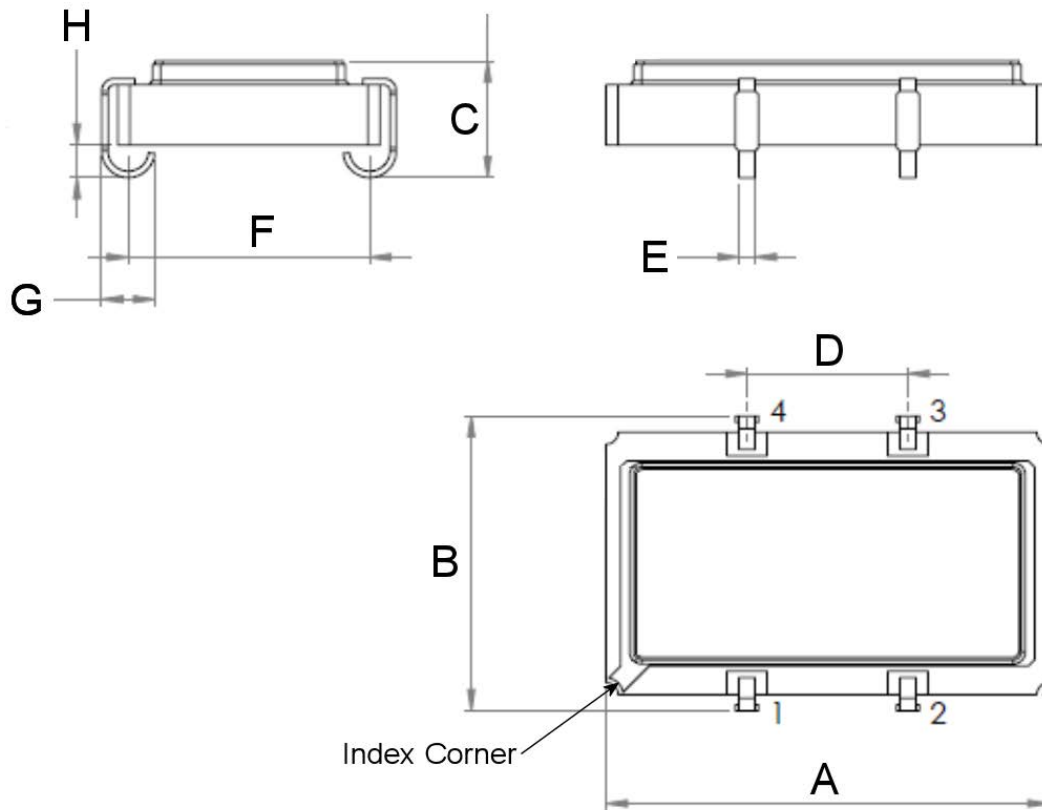


Symbols	Dimensions mm		Notes
	Min	Max	
A	-	20.7	
B	-	13.1	
C	-	5.45	
D	15.24 BSC		2 places
E	7.62 BSC		All leads
F	2.54 BSC		All leads
G	6.22	6.48	All leads
ØH	0.25	0.65	All leads
J	-	6	4 places

**NOTES:**

1. The terminal identification is specified by reference to the index corner as shown. See Para. 1.7 for the terminal connections.

1.6.6 J-Lead Package (JL2) – 4 leads

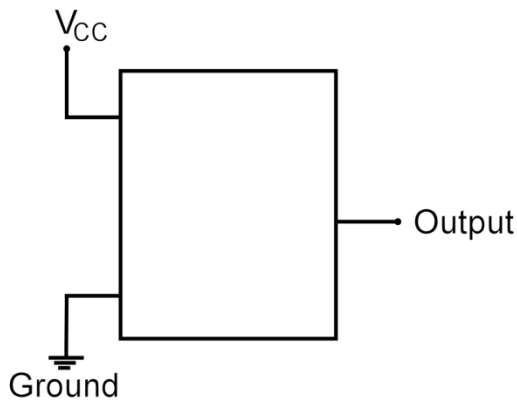


Symbols	Dimensions mm		Notes
	Min	Max	
A	13.72	14.22	
B	8.8	9.8	2 places
C	-	4.2	All leads
D	4.93	5.23	2 places
E	0.46	0.56	All leads
F	7.42	7.82	All leads
G	1.58	1.78	All leads
H	0.89	1.15	All leads

**NOTES:**

1. The terminal identification is specified by reference to the index corner as shown. See Para. 1.7 for the terminal connections.

1.7 FUNCTIONAL DIAGRAM



Variant Number	Case	Terminal Number				Notes
		Output	V <sub>CC</sub>	Ground	Not Connected	
01, 07	FP1	8	14	1, 2, 3, 4, 7, 10, 11, 12, 13	5, 6, 9	1, 2
02, 08	FP2	11	13	1, 2, 3, 4, 5, 6, 7, 10, 14, 15, 16, 17, 18, 19, 20	8, 9, 12	1, 2
03, 09	FP3	7	12	1, 2, 3, 6, 9, 10, 11	4, 5, 8	1, 2
04, 10	FP4	10	8	1, 2, 3, 4, 5, 9, 12, 13, 14, 15, 16	6, 7, 11	1, 2
05, 11	DIL1	8	14	7	1, 2, 3, 4, 5, 6, 9, 10, 11, 12, 13	1, 2
06, 12	JL2	3	4	2	1	1, 2

**NOTES:**

1. The case is connected to Ground.
2. Not connected pins must be connected to a potential (e.g. Ground)

1.8 MATERIALS AND FINISHES

Materials and finishes shall be as follows:

- (a) Case
  - The FP1, FP2, FP3, FP4 and DIL1 cases shall be hermetically sealed, and have a metal body with hard glass seals and a seam sealed metal lid.
  - The JL2 case shall be hermetically sealed, and have a ceramic body with brazed leads and a seam sealed lid.
- (b) Terminals
  - As specified in Para. 1.4.3 Component Type Variants.

## 2 REQUIREMENTS

### 2.1 GENERAL

The complete requirements for procurement of the components specified herein are as stated in this specification and the ESCC Generic Specification. Permitted deviations from the Generic Specification, applicable to this specification only, are listed below.

Permitted deviations from the Generic Specification and this Detail Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalent to the ESCC requirement and do not affect the component's reliability, are listed in the appendices attached to this specification.

#### 2.1.1 Oscillator Class

The components specified herein shall satisfy the requirements Class 2 Oscillators in accordance with the Generic Specification.

#### 2.1.2 Deviations from the Generic Specification

None.

### 2.2 MARKING

The marking shall be in accordance with the requirements of ESCC Basic Specification No. [21700](#) and as follows.

The information to be marked on the component shall be:

- (a) Terminal identification (see Para. 1.6).
- (b) The ESCC Qualified Component symbol (for ESCC qualified components only).
- (c) The ESCC Component Number (see Para. 1.4.1).
- (d) Traceability information.

2.3 ELECTRICAL MEASUREMENTS AT ROOM, HIGH AND LOW TEMPERATURES

Electrical measurements shall be performed at room, high and low temperatures. Consolidated notes are given in Para. 2.3.3.

2.3.1 Room Temperature Electrical Measurements

Characteristics	Symbols	Test Method	Test Conditions Note 1	Limits		Units
				Min	Max	
Input Current	$I_{IN}$	ESCC No. 24200	For 4MHz ≤ f <sub>Nom</sub> < 20MHz: For 20MHz ≤ f <sub>Nom</sub> < 50MHz: For 50MHz ≤ f <sub>Nom</sub> ≤ 100MHz:	- - -	20 25 30	mA
Output Waveform	-	ESCC No. 24200		Symmetrical Square Wave		-
Output Voltage High Level Variants 01 to 06: Variants 07 to 12:	V <sub>OH</sub>	ESCC No. 24200		2.4 4.5	- -	V
Output Voltage Low Level Variants 01 to 06: Variants 07 to 12:	V <sub>OL</sub>	ESCC No. 24200		- -	0.4 0.5	V
Frequency Accuracy	$\Delta f/f_{Nom}$	ESCC No. 24200	At T <sub>amb</sub> = +25 ±1°C Referred to f <sub>Nom</sub>	-	±25	ppm
Frequency-Voltage Tolerance Variants 01 to 06: Variants 07 to 12:	$\Delta f/f(V)$	ESCC No. 24200	At T <sub>amb</sub> = +25 ±1°C Referred to f at V <sub>CCNom</sub> For 2.97V, 3.3V & 3.63V: For 4.5V, 5V & 5.5V:	- -	±3 ±3	ppm
Frequency-Load Tolerance	$\Delta f/f(L)$	ESCC No. 24200	At T <sub>amb</sub> = +25 ±1°C For C <sub>L</sub> = C <sub>LMin</sub> , C <sub>LNom</sub> & C <sub>LMax</sub> , R <sub>L</sub> = 1kΩ, Referred to f at C <sub>LNom</sub>	-	±5	ppm
Startup Time	t <sub>su</sub>	ESCC No. 24200		-	10	ms
Rise Time	t <sub>r</sub>	ESCC No. 24200	For 4MHz ≤ f <sub>Nom</sub> < 16MHz: For 16MHz ≤ f <sub>Nom</sub> ≤ 100MHz:	- -	10 7	ns
Fall Time	t <sub>f</sub>	ESCC No. 24200	For 4MHz ≤ f <sub>Nom</sub> < 16MHz: For 16MHz ≤ f <sub>Nom</sub> ≤ 100MHz:	- -	10 7	ns
Duty Cycle	DC	ESCC No. 24200		45	55	%
Ageing Analysis	$\Delta f/f$	ESCC No. 3503	Ageing Period = 1 year Note 3	-	±5	ppm



2.3.2 High and Low Temperatures Electrical Measurements

Characteristics	Symbols	Test Method	Test Conditions Note 1	Limits		Units
				Min	Max	
Input Current	I <sub>IN</sub>	ESCC No. 24200	At T <sub>amb</sub> = -55 (+5 -0)°C and +110 (+0 -5)°C For 4MHz ≤ f <sub>Nom</sub> < 20MHz: For 20MHz ≤ f <sub>Nom</sub> < 50MHz: For 50MHz ≤ f <sub>Nom</sub> ≤ 100MHz:	- - -	20 25 30	mA
Output Waveform	-	ESCC No. 24200	At T <sub>amb</sub> = -55 (+5 -0)°C and +110 (+0 -5)°C	Symmetrical Square Wave		-
Output Voltage High Level Variants 01 to 06: Variants 07 to 12:	V <sub>OH</sub>	ESCC No. 24200	At T <sub>amb</sub> = -55 (+5 -0)°C and +110 (+0 -5)°C	2.4 4.5	- -	V
Output Voltage Low Level Variants 01 to 06: Variants 07 to 12:	V <sub>OL</sub>	ESCC No. 24200	At T <sub>amb</sub> = -55 (+5 -0)°C and +110 (+0 -5)°C	- -	0.4 0.5	V
Frequency-Temperature Stability	Δf/f(T)	ESCC No. 24200	At T <sub>amb</sub> = -55 (+1 -0)°C to +110 (+0 -1)°C. Note 2 Referred to f at T <sub>amb</sub> = +25 ±1°C	-	50	ppm
Frequency-Voltage Tolerance Variants 01 to 06: Variants 07 to 12:	Δf/f(V)	ESCC No. 24200	At T <sub>amb</sub> = -55 (+1 -0)°C and +110 (+0 -1)°C Referred to f at V <sub>CCNom</sub> For 2.97V, 3.3V & 3.63V: For 4.5V, 5V & 5.5V:	- -	±3 ±3	ppm
Startup Time	t <sub>su</sub>	ESCC No. 24200	At T <sub>amb</sub> = -55 (+5 -0)°C and +110 (+0 -5)°C		10	ms
Rise Time	t <sub>r</sub>	ESCC No. 24200	At T <sub>amb</sub> = -55 (+5 -0)°C and +110 (+0 -5)°C For 4MHz ≤ f <sub>Nom</sub> < 16MHz: For 16MHz ≤ f <sub>Nom</sub> ≤ 100MHz:	- -	10 7	ns
Fall Time	t <sub>f</sub>	ESCC No. 24200	At T <sub>amb</sub> = -55 (+5 -0)°C and +110 (+0 -5)°C For 4MHz ≤ f <sub>Nom</sub> < 16MHz: For 16MHz ≤ f <sub>Nom</sub> ≤ 100MHz:	- -	10 7	ns
Duty Cycle	DC	ESCC No. 24200	At T <sub>amb</sub> = -55 (+5 -0)°C and +110 (+0 -5)°C	45	55	%

2.3.3 Notes to Paras. 2.3.1 and 2.3.2 Room, High and Low Electrical Measurements

1. Unless otherwise specified, the measurements shall be performed at T<sub>amb</sub> = +22 ±3°C and the component under test shall be operated at V<sub>CCNom</sub> with an output load of C<sub>LNom</sub> in parallel with R<sub>L</sub> = 1kΩ. V<sub>CCNom</sub> and C<sub>LNom</sub> are specified in Para. 1.5 Maximum Ratings.
2. Frequency-Temperature Stability shall be measured at a minimum of 10 equally spaced increments over the specified temperature range.
3. All measurements acquired during Frequency Ageing shall be taken into account when performing Ageing Analysis.

2.4 PARAMETER DRIFT VALUES

Unless otherwise specified, the measurements shall be performed at  $T_{amb} = +22 \pm 3^{\circ}C$ .

The test methods and test conditions shall be as per the corresponding test defined in Para. 2.3.1 Room Temperature Electrical Measurements.

The drift values ( $\Delta$ ) shall not be exceeded for each characteristic specified. The corresponding absolute limit values for each characteristic shall not be exceeded.

Characteristics	Symbols	Limits			Units
		Drift Value $\Delta$	Absolute		
			Min	Max	
Input Current For $4MHz \leq f_{Nom} < 20MHz$ : For $20MHz \leq f_{Nom} < 50MHz$ : For $50MHz \leq f_{Nom} \leq 100MHz$ :	$I_{IN}$	$\pm 5\%$ $\pm 5\%$ $\pm 5\%$	- - -	20 25 30	mA
Frequency Accuracy Initial measurement: Final measurement:	$\Delta f/f_{Nom}$	$\pm 10$	- -	$\pm 15$ $\pm 25$	ppm

2.5 INTERMEDIATE AND END-POINT ELECTRICAL MEASUREMENTS

Unless otherwise specified, the measurements shall be performed at  $T_{amb} = +22 \pm 3 \text{ }^\circ\text{C}$ .

The test methods and test conditions shall be as per the corresponding test defined in Para. 2.3.1 Room Temperature Electrical Measurements or Para. 2.3.2 High and Low Temperatures Electrical Measurements, as follows.

The drift values ( $\Delta$ ) shall not be exceeded for each characteristic specified. Unless otherwise specified, the corresponding absolute limit values for each characteristic shall not be exceeded.

Characteristics	Symbols	Test Conditions	Limits			Units
			Drift Value $\Delta$	Absolute		
				Min	Max	
Input Current For $4\text{MHz} \leq f_{Nom} < 20\text{MHz}$ : For $20\text{MHz} \leq f_{Nom} < 50\text{MHz}$ : For $50\text{MHz} \leq f_{Nom} \leq 100\text{MHz}$ :	$I_{IN}$	As per Para. 2.3.1	- - -	- - -	20 25 30	mA
Output Waveform	-	As per Para. 2.3.1	-	Symmetrical Square Wave		-
Output Voltage High Level Variants 01 to 06: Variants 07 to 12:	$V_{OH}$	As per Para. 2.3.1	- -	2.4 4.5	- -	V
Output Voltage Low Level Variants 01 to 06: Variants 07 to 12:	$V_{OL}$	As per Para. 2.3.1	- -	- -	0.4 0.5	V
Frequency Accuracy	$\Delta f/f_{Nom}$	As per Para. 2.3.1	$\pm 8.5$ (1)	-	$\pm 25$ (2)	ppm
Frequency-Temperature Stability	$\Delta f/f(T)$	As per Para. 2.3.1	-	-	50	ppm
Rise Time For $4\text{MHz} \leq f_{Nom} < 16\text{MHz}$ : For $16\text{MHz} \leq f_{Nom} \leq 100\text{MHz}$ :	$t_r$	As per Para. 2.3.1	- -	- -	10 7	ns
Fall Time For $4\text{MHz} \leq f_{Nom} < 16\text{MHz}$ : For $16\text{MHz} \leq f_{Nom} \leq 100\text{MHz}$ :	$t_r$	As per Para. 2.3.1	- -	- -	10 7	ns
Duty Cycle	DC	As per Para. 2.3.1	-	45	55	%

**NOTES:**

1. Drift value ( $\Delta$ ) is only applicable to testing during the Endurance Subgroup.
2. Absolute limit is only applicable to testing during the Environmental/Mechanical Subgroup.

2.6 BURN-IN CONDITIONS

The test conditions for Burn-in, tested as specified in the ESCC Generic Specification, shall be as follows:

- (a) Output Load:  $C_{LNom}$  in parallel with  $R_L = 1\text{k}\Omega$ .  $C_{LNom}$  is specified in Para. 1.5 Maximum Ratings.

## 2.7 FREQUENCY AGEING CONDITIONS

The test conditions for Frequency Ageing, tested as specified in the ESCC Generic Specification, shall be as follows:

- (a) Output Load:  $C_{LNom}$  in parallel with  $R_L = 1k\Omega$ .  $C_{LNom}$  is specified in Para. 1.5 Maximum Ratings.

## 2.8 OPERATING LIFE CONDITIONS

The test conditions for Operating Life, tested as specified in the ESCC Generic Specification, shall be as follows:

- (a) Output Load:  $C_{LNom}$  in parallel with  $R_L = 1k\Omega$ .  $C_{LNom}$  is specified in Para. 1.5 Maximum Ratings.

## 2.9 TOTAL DOSE RADIATION TESTING

All lots shall be irradiated in accordance with ESCC Basic Specification No. [22900](#), low dose rate (window 2: 36rad(Si) to 360rad(Si) per hour).

### 2.9.1 Bias Conditions and Total Dose Level for Total Dose Radiation Testing

The following bias condition (worst-case) shall be used for Total Dose Radiation Testing at  $T_{amb} = +22 \pm 3^\circ\text{C}$ :

With Supply Voltage:

- Variants 01 to 06:  $V_{CC} = 3.63\text{V}$  during irradiation.
- Variants 07 to 12:  $V_{CC} = 5.5\text{V}$  during irradiation.

The total dose level applied shall be as specified in Para. 1.4.3 or in the Purchase Order.

2.9.2 Electrical Measurements for Total Dose Radiation Testing

Prior to irradiation testing the devices shall have successfully met Para. 2.3.1 Room Temperature Electrical Measurements specified herein.

Unless otherwise specified, the measurements shall be performed at  $T_{amb} = +22 \pm 3^{\circ}\text{C}$ .

Unless otherwise specified, the test methods and test conditions shall be as per the corresponding test defined in Para. 2.3.1 Room Temperature Electrical Measurements.

The parameters to be measured during irradiation testing, on completion of irradiation testing, after 24 hours anneal at Room Temperature and after 168 hours anneal at  $T_{amb} = +100 \pm 3^{\circ}\text{C}$  are shown below.

Characteristics	Symbols	Limits		Units
		Absolute		
		Min	Max	
Input Current For $4\text{MHz} \leq f_{Nom} < 20\text{MHz}$ : For $20\text{MHz} \leq f_{Nom} < 50\text{MHz}$ : For $50\text{MHz} \leq f_{Nom} \leq 100\text{MHz}$ :	$I_{IN}$	-	20 25 30	mA
Output Waveform	-	Symmetrical Square Wave		-
Output Voltage High Level Variants 01 to 06: Variants 07 to 12:	$V_{OH}$	2.4 4.5	- -	V
Output Voltage Low Level Variants 01 to 06: Variants 07 to 12:	$V_{OL}$	- -	0.4 0.5	V
Frequency Accuracy	$\Delta f/f_{Nom}$	-	$\pm 25$	ppm
Rise Time For $4\text{MHz} \leq f_{Nom} < 16\text{MHz}$ : For $16\text{MHz} \leq f_{Nom} \leq 100\text{MHz}$ :	$t_r$	- -	10 7	ns
Fall Time For $4\text{MHz} \leq f_{Nom} < 16\text{MHz}$ : For $16\text{MHz} \leq f_{Nom} \leq 100\text{MHz}$ :	$t_f$	- -	10 7	ns
Duty Cycle	DC	45	55	%